

CSD16340Q3 25-V N-Channel NexFET™ Power MOSFET

1 Features

- Optimized for 5 V Gate Drive
- Resistance Rated at $V_{GS} = 2.5$ V
- Ultra-Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 3.3-mm x 3.3-mm Plastic Package

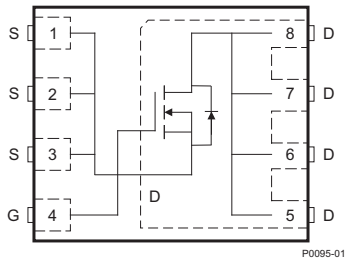
2 Applications

- Point of Load Synchronous Buck Converter for Applications in Networking, Telecom, and Computing Systems
- Optimized for Control or Synchronous FET Applications

3 Description

This 25 V, 3.8 mΩ, 3.3 x 3.3 mm SON NexFET™ power MOSFET is designed to minimize losses in power conversion and optimized for 5 V gate drive applications.

Top View



Product Summary

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	25	V
Q_g	Gate Charge Total (4.5 V)	6.5	nC
Q_{gd}	Gate Charge Gate-to-Drain	1.2	nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = 2.5$ V	6.1 mΩ
		$V_{GS} = 4.5$ V	4.3 mΩ
		$V_{GS} = 8$ V	3.8 mΩ
V_{th}	Threshold Voltage	0.85	V

Ordering Information⁽¹⁾

Device	Media	Qty	Package	Ship
CSD16340Q3	13-Inch Reel	2500	SON 3.3 x 3.3 mm Plastic Package	Tape and Reel
CSD16340Q3T	7-Inch Reel	250		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

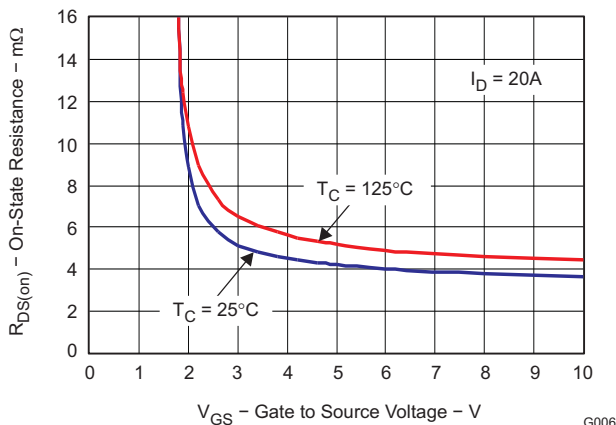
Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	25	V
V_{GS}	Gate-to-Source Voltage	+10 / -8	V
I_D	Continuous Drain Current, $T_C = 25^\circ\text{C}$	60	A
	Continuous Drain Current ⁽¹⁾	21	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾	115	A
P_D	Power Dissipation ⁽¹⁾	3	W
T_J, T_{stg}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
E_{AS}	Avalanche Energy, single pulse $I_D = 40$ A, $L = 0.1$ mH, $R_G = 25$ Ω	80	mJ

(1) Typical $R_{\theta JA} = 39^\circ\text{C/W}$ on 1in² Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width ≤ 300 μs , duty cycle $\leq 2\%$

$R_{DS(on)}$ vs V_{GS}



Gate Charge

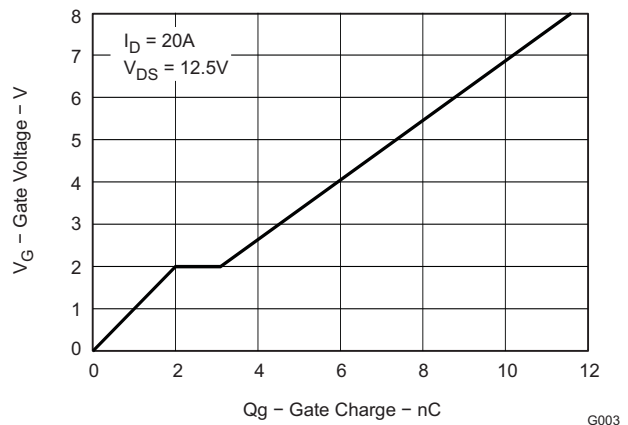


Table of Contents

1 Features 1 2 Applications 1 3 Description 1 4 Revision History 2 5 Specifications 3 5.1 Electrical Characteristics..... 3 5.2 Thermal Information 4 5.3 Typical MOSFET Characteristics..... 5 6 Device and Documentation Support 8	6.1 Trademarks 8 6.2 Electrostatic Discharge Caution 8 6.3 Glossary 8 7 Mechanical, Packaging, and Orderable Information 9 7.1 Q3 Package Dimensions 9 7.2 Recommended PCB Pattern..... 10 7.3 Recommended Stencil Opening 10 7.4 Q3 Tape and Reel Information..... 11
--	--

4 Revision History

Changes from Revision D (November 2011) to Revision E	Page
• Added 7" reel to Ordering Information	1
• Updated Mechanical Information	9
Changes from Revision C (June 2011) to Revision D	Page
• Replaced the THERMAL CHARACTERISTICS table with the new Thermal Information Table.....	4
• Replaced Figure 10 - Maximum Safe Operating Area	6
Changes from Revision B (September 2010) to Revision C	Page
• Deleted the Package Marking Information section	9
Changes from Revision A (January 2010) to Revision B	Page
• Changed Figure 2 , reversed the order of the V_{GS} labels.....	5
Changes from Original (December 2009) to Revision A	Page
• Changed Q_g in the PRODUCT SUMMARY table from: 6.8 To 6.5 nC	1

5 Specifications

5.1 Electrical Characteristics

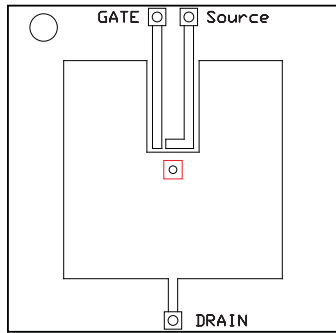
(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
B _V DSS	Drain-to-Source Voltage	V _{GS} = 0 V, I _{DS} = 250 μA	25			V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = 20 V			1	μA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = +10/-8 V			100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _{DS} = 250 μA	0.6	0.85	1.1	V
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = 2.5 V, I _{DS} = 20 A		6.1	7.8	mΩ
		V _{GS} = 4.5 V, I _{DS} = 20 A		4.3	5.5	mΩ
		V _{GS} = 8 V, I _{DS} = 20 A		3.8	4.5	mΩ
g _{fs}	Transconductance	V _{DS} = 15 V, I _{DS} = 20 A		121		S
DYNAMIC CHARACTERISTICS						
C _{ISS}	Input Capacitance	V _{GS} = 0 V, V _{DS} = 12.5 V, f = 1 MHz		1050	1350	pF
C _{OSS}	Output Capacitance			730	950	pF
C _{RSS}	Reverse Transfer Capacitance			53	69	pF
R _g	Series Gate Resistance			1.5	3	Ω
Q _g	Gate Charge Total (4.5 V)	V _{DS} = 12.5 V, I _D = 20 A		6.5	9.2	nC
Q _{gd}	Gate Charge Gate-to-Drain			1.2		nC
Q _{gs}	Gate Charge Gate-to-Source			2.1		nC
Q _{g(th)}	Gate Charge at V _{th}			1		nC
Q _{OSS}	Output Charge	V _{DS} = 13 V, V _{GS} = 0 V		15		nC
t _{d(on)}	Turn On Delay Time	V _{DS} = 12.5 V, V _{GS} = 4.5 V, I _D = 20 A R _G = 2 Ω		4.8		ns
t _r	Rise Time			16.1		ns
t _{d(off)}	Turn Off Delay Time			13.8		ns
t _f	Fall Time			5.2		ns
DIODE CHARACTERISTICS						
V _{SD}	Diode Forward Voltage	I _S = 20 A, V _{GS} = 0 V		0.8	1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = 13 V, I _F = 20 A, di/dt = 300 A/μs		14.5		nC
t _{rr}	Reverse Recovery Time				20	

5.2 Thermal Information

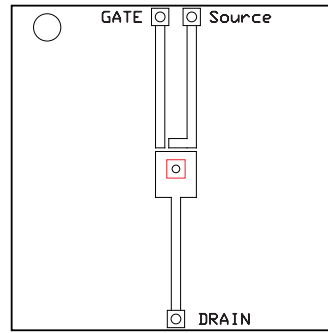
THERMAL METRIC ⁽¹⁾⁽²⁾		CSD16340Q3	UNITS
		Q3 (8 PINS)	
θ_{JA}	Junction-to-Ambient Thermal Resistance	42.0	°C/W
θ_{JCTop}	Junction-to-Case (top) Thermal Resistance	20.6	
θ_{JB}	Junction-to-Board Thermal Resistance	8.8	
Ψ_{JT}	Junction-to-Top Characterization Parameter	0.3	
Ψ_{JB}	Junction-to-Board Characterization Parameter	8.7	
θ_{JCbot}	Junction-to-Case (bottom) Thermal Resistance	0.1	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).
 (2) For thermal estimates of this device based on PCB copper area, see the [TI PCB Thermal Calculator](#).



M0161-01

Max $R_{\theta JA} = 58^{\circ}\text{C/W}$
 when mounted on
 1 inch² of 2 oz. Cu.



M0161-02

Max $R_{\theta JA} = 162^{\circ}\text{C/W}$
 when mounted on
 minimum pad area of
 2 oz. Cu.

5.3 Typical MOSFET Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)

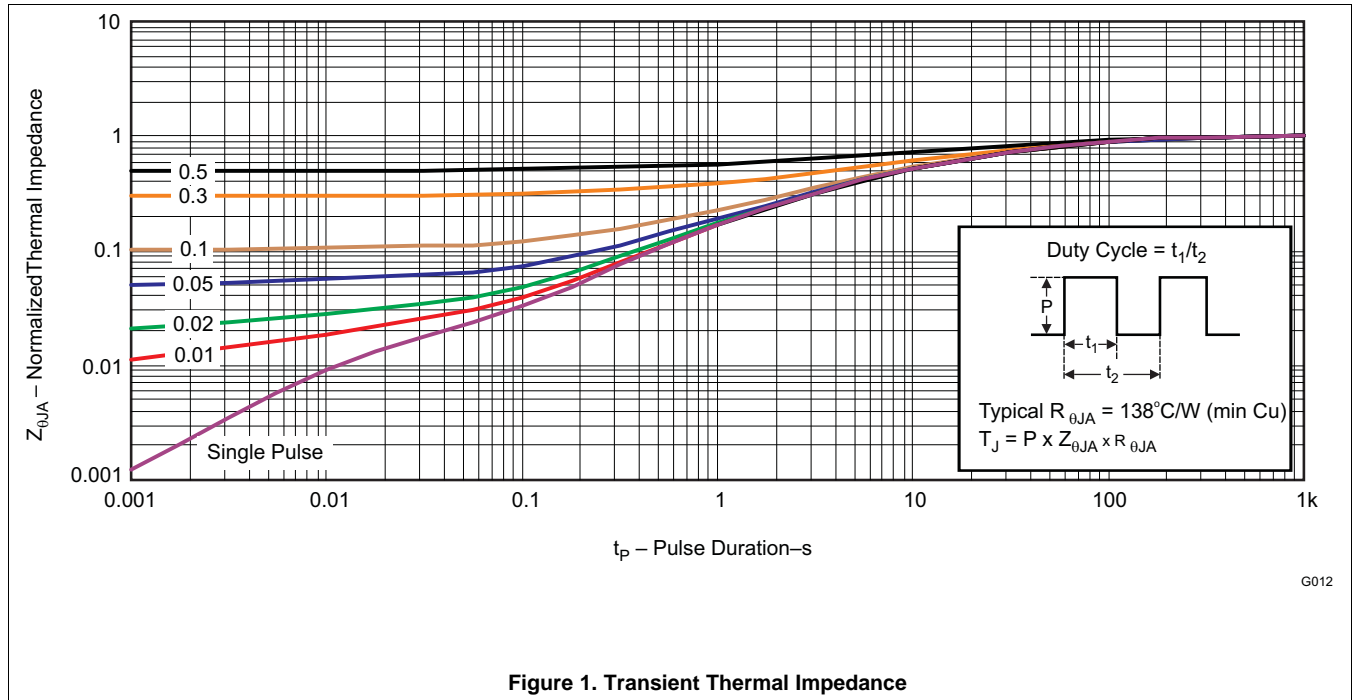


Figure 1. Transient Thermal Impedance

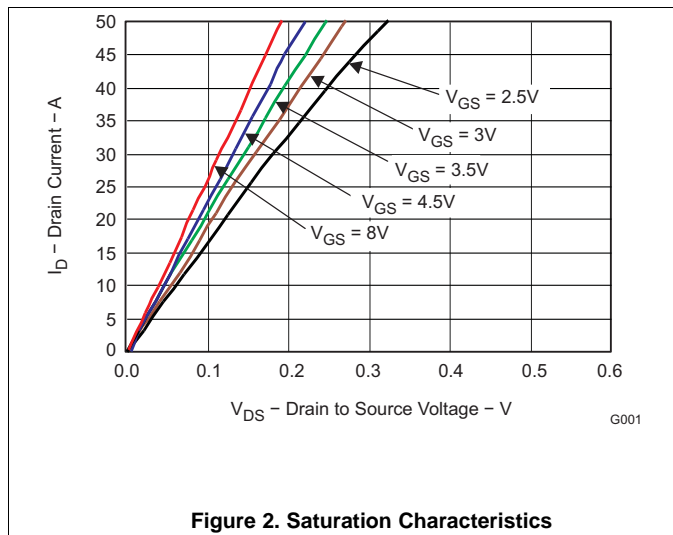


Figure 2. Saturation Characteristics

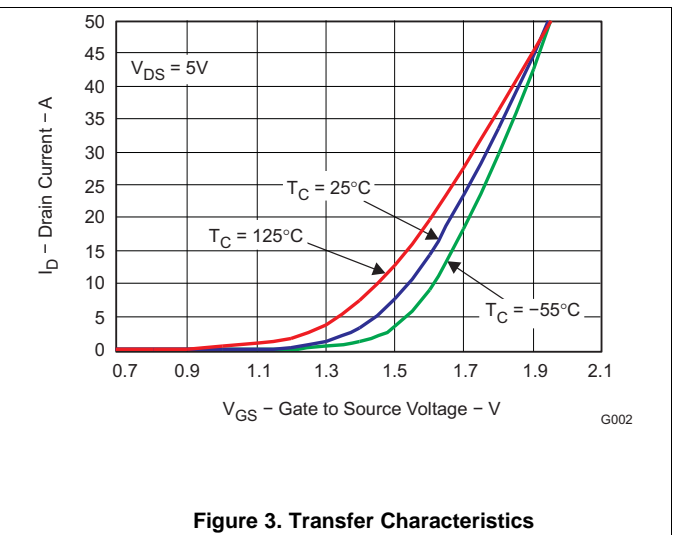
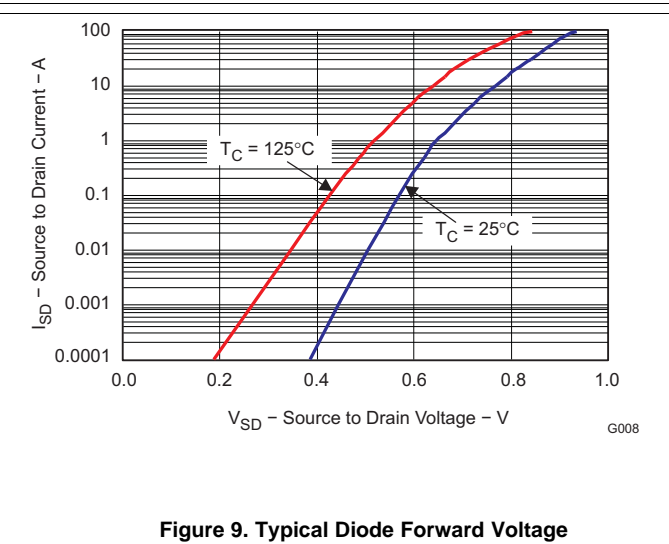
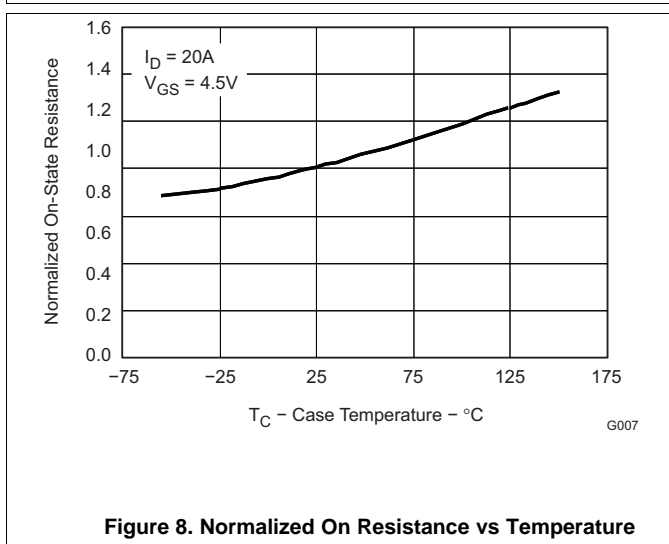
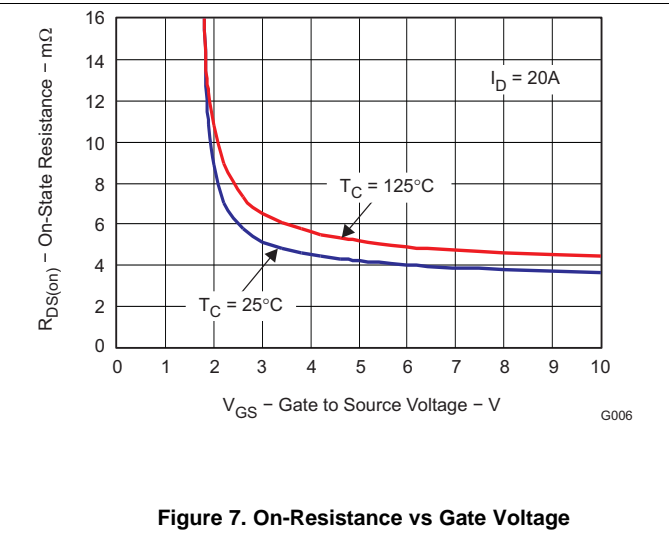
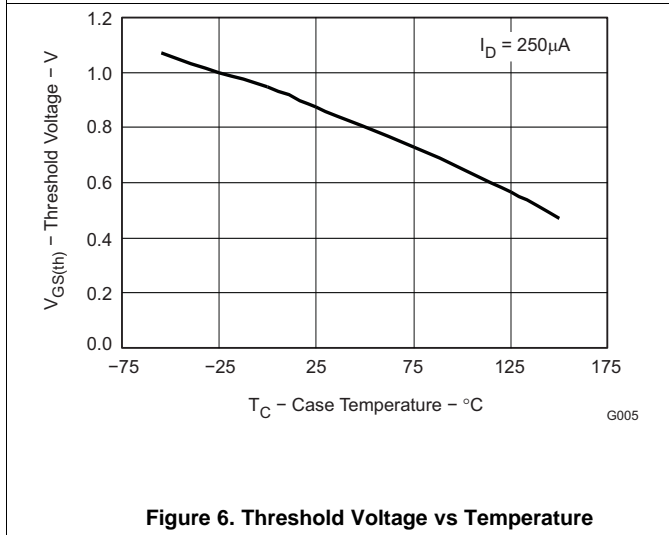
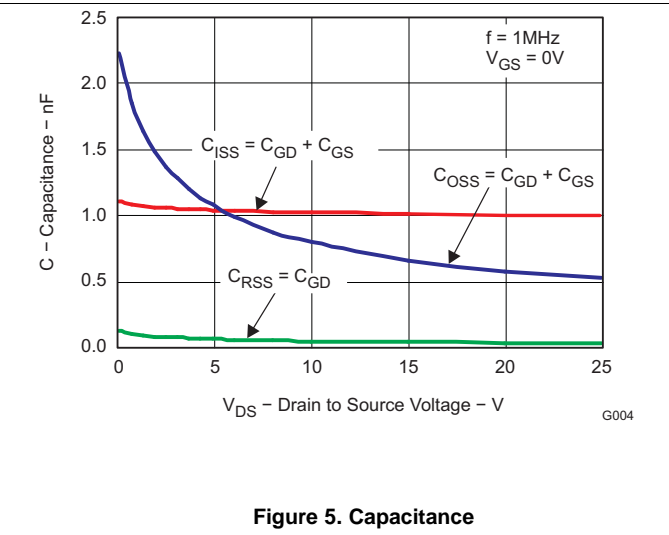
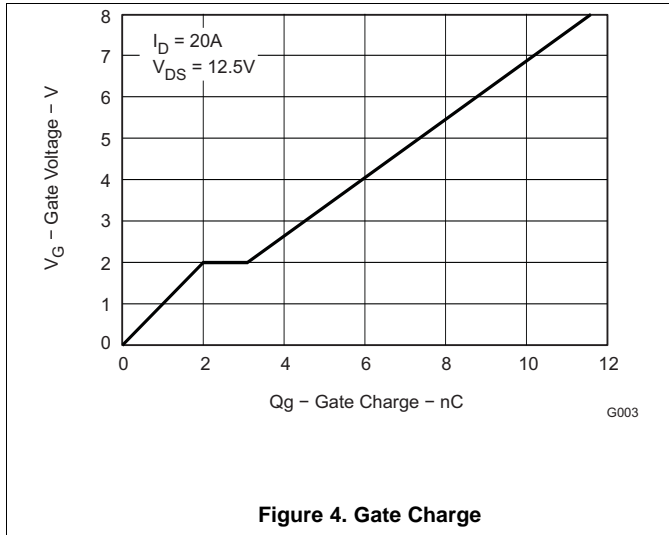


Figure 3. Transfer Characteristics

Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

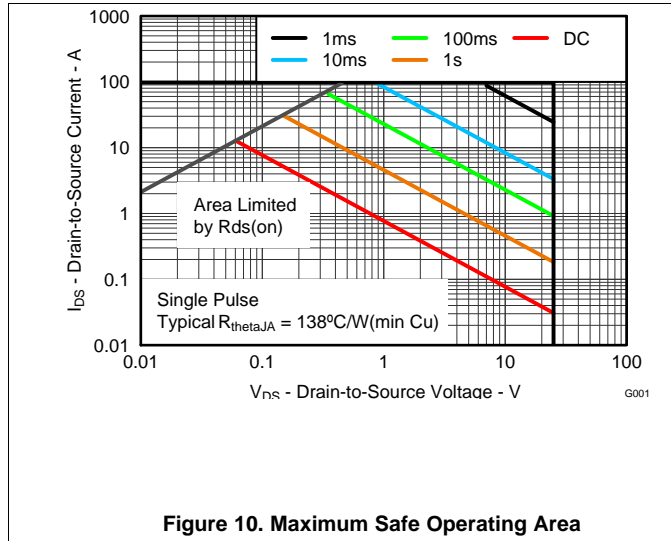


Figure 10. Maximum Safe Operating Area

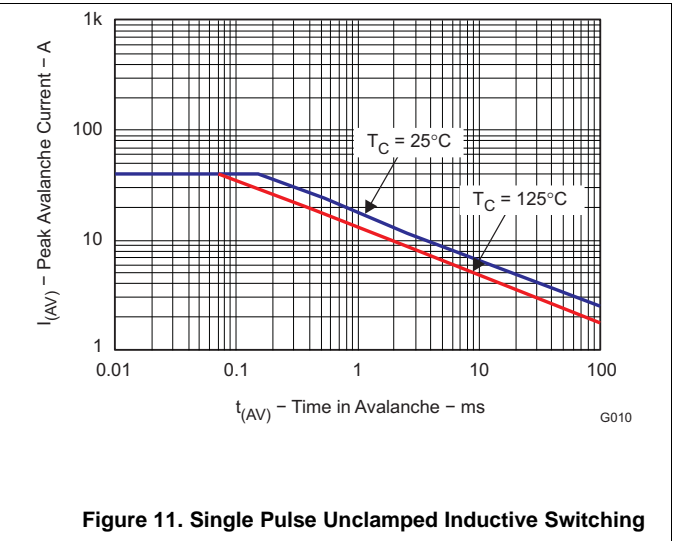


Figure 11. Single Pulse Unclamped Inductive Switching

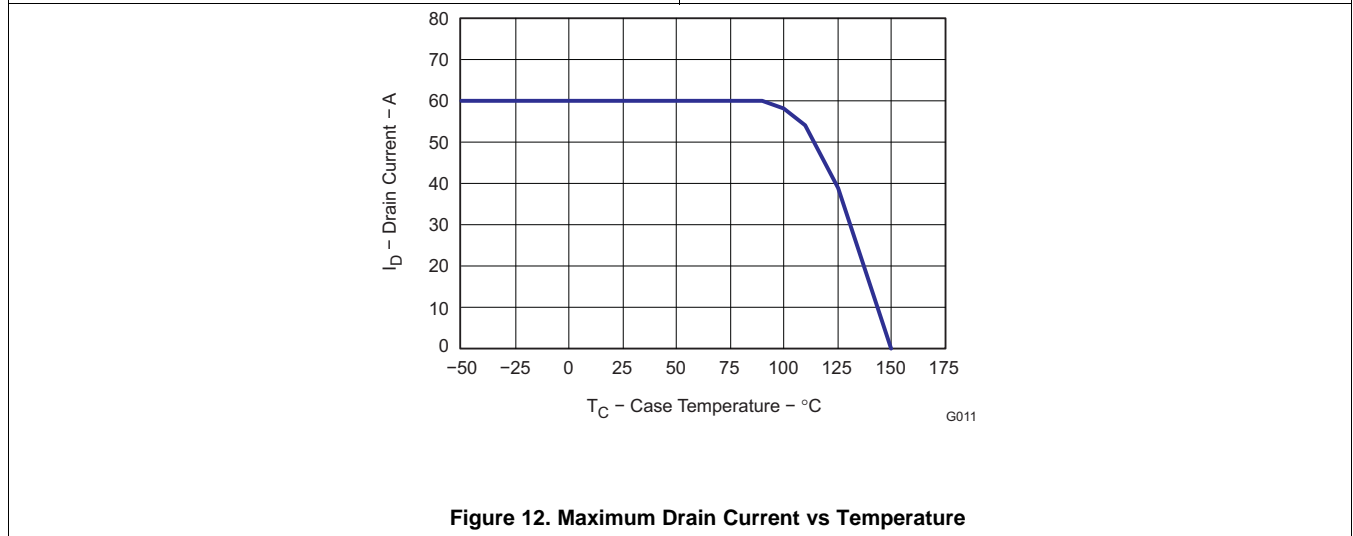


Figure 12. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Trademarks

NexFET is a trademark of Texas Instruments.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

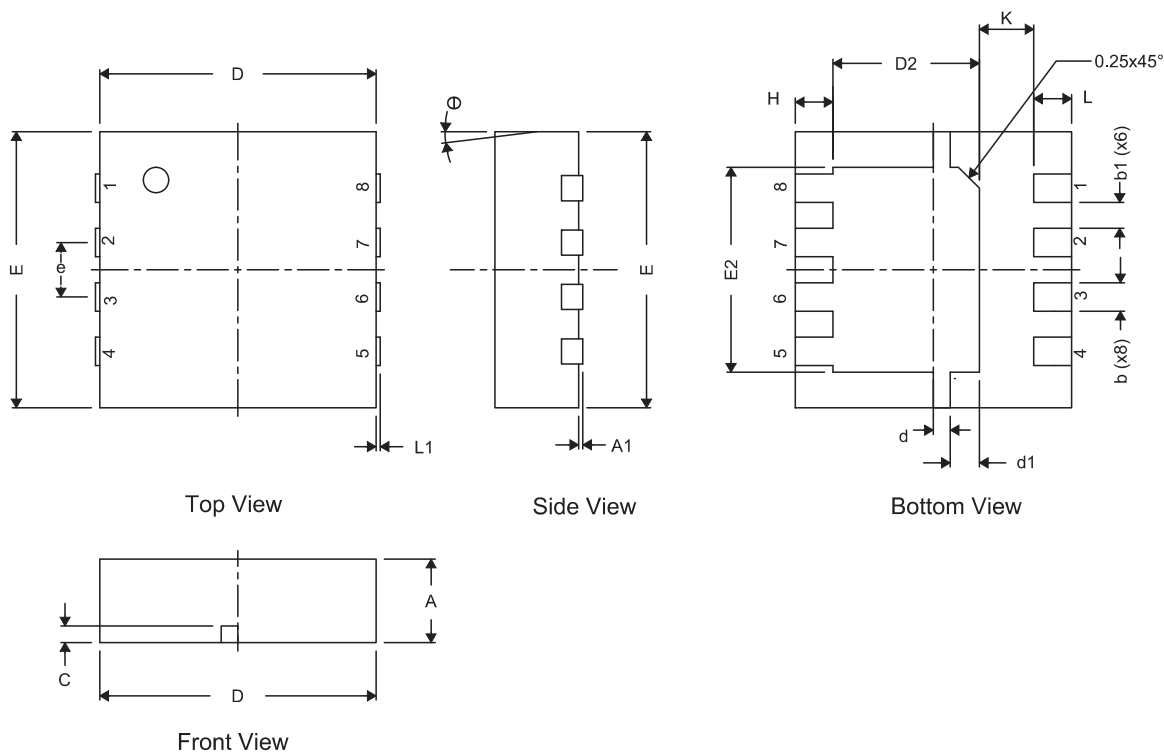
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical, Packaging, and Orderable Information

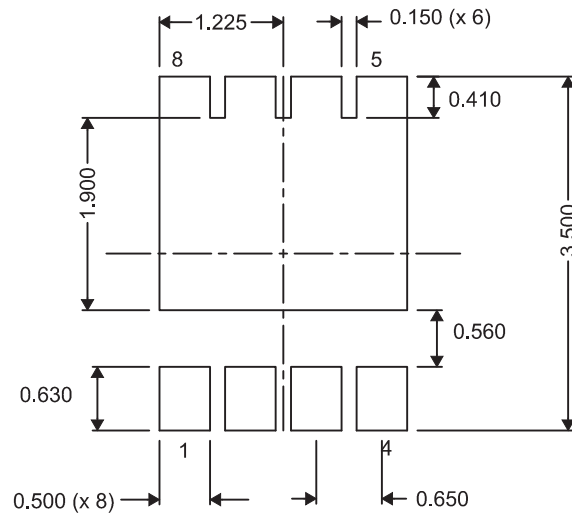
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q3 Package Dimensions



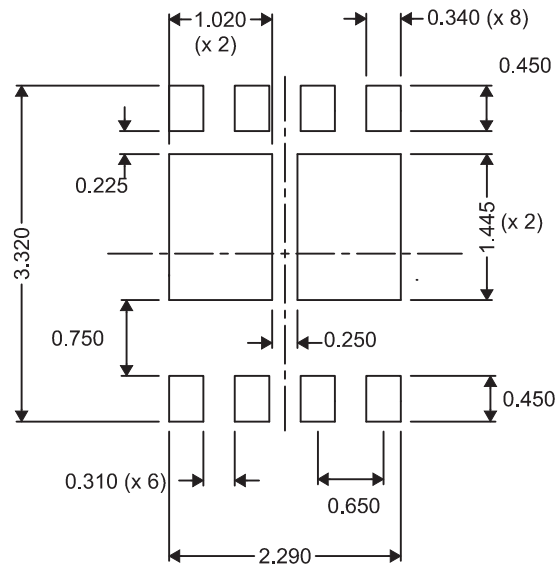
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.950	1.000	1.100	0.037	0.039	0.043
A1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.280	0.340	0.400	0.011	0.013	0.016
b1	0.310 NOM			0.012 NOM		
c	0.150	0.200	0.250	0.006	0.008	0.010
D	3.200	3.300	3.400	0.126	0.130	0.134
D2	1.650	1.750	1.800	0.065	0.069	0.071
d	0.150	0.200	0.250	0.006	0.008	0.010
d1	0.300	0.350	0.400	0.012	0.014	0.016
E	3.200	3.300	3.400	0.126	0.130	0.134
E2	2.350	2.450	2.550	0.093	0.096	0.100
e	0.650 TYP			0.026		
H	0.35	0.450	0.550	0.014	0.018	0.022
K	0.650 TYP			0.026 TYP		
L	0.35	0.450	0.550	0.014	0.018	0.022
L1	0	—	0	0	—	0
θ	0	—	0	0	—	0

7.2 Recommended PCB Pattern



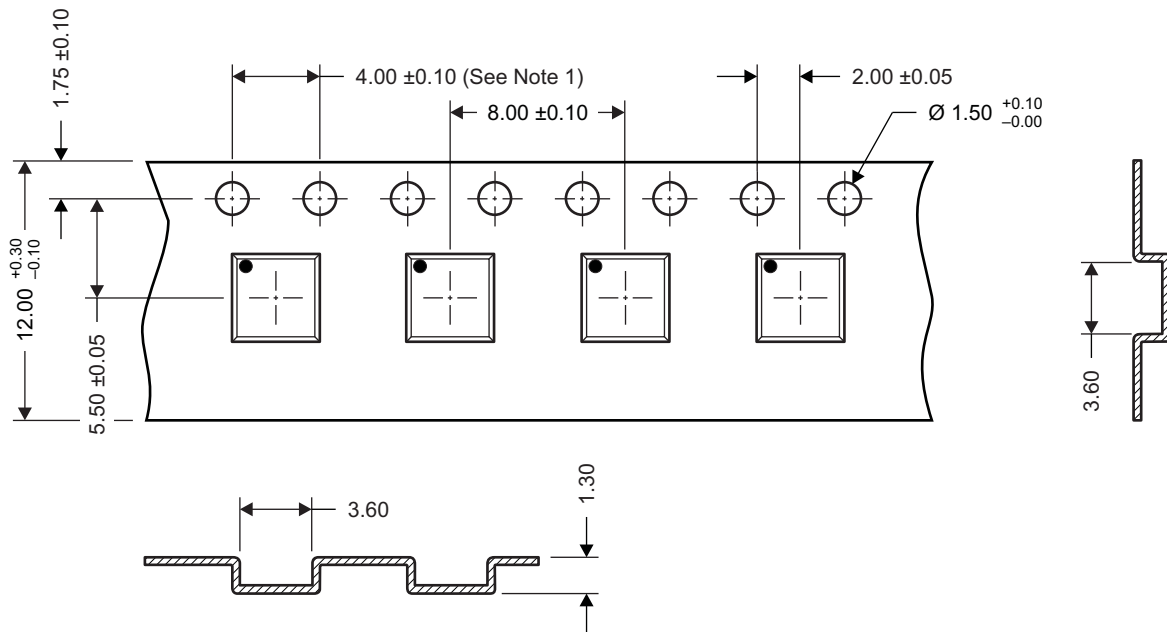
For recommended circuit layout for PCB designs, see application note [SLPA005](#) – *Reducing Ringing Through PCB Layout Techniques*.

7.3 Recommended Stencil Opening



All dimensions are in mm, unless otherwise specified.

7.4 Q3 Tape and Reel Information



M0144-01

Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2
2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
3. Material: black static dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified).
5. Thickness: 0.30 ± 0.05 mm
6. MSL1 260°C (IR and Convection) PbF-Reflow Compatible

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16340Q3	VSON-CLIP	DQG	8	2500	330.0	12.4	3.6	3.6	1.2	8.0	12.0	Q1
CSD16340Q3T	VSON-CLIP	DQG	8	250	330.0	12.4	3.6	3.6	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16340Q3	VSON-CLIP	DQG	8	2500	336.6	336.6	41.3
CSD16340Q3T	VSON-CLIP	DQG	8	250	336.6	336.6	41.3

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com